



T-1³/₄ (5 mm) Precision Optical Performance AlInGaP LED Lamps

Technical Data

Features

- Well Defined and Smooth Spatial Radiation Patterns
- Wide Viewing Angle
- Tinted Diffused Lamp
- High Luminous Output
- Colors:
590/592 nm Amber
615/617 nm Reddish-Orange
626/630 nm Red
- High Operating Temperature:
 $T_{JLED} = +130^\circ\text{C}$
- Superior Resistance to Moisture

Benefits

- Viewing Angles Match Traffic Management Sign Requirements
- Colors Meet Automotive Specifications
- Superior Performance in Outdoor Environments
- Suitable for Autoinsertion onto PC Boards

Applications

- **Traffic Management:**
Variable Message Signs
Traffic Management Signs
- **Commercial Indoor/Outdoor Advertising:**
Signs
Marquees
Passenger Information
- **Automotive:**
Exterior and Interior Lights

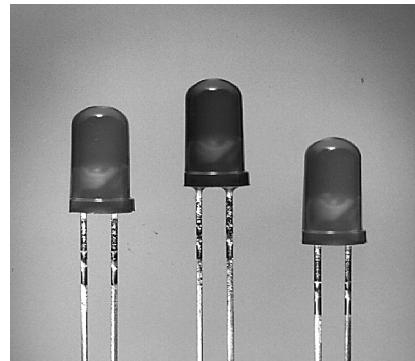
Description

These Precision Optical Performance AlInGaP LEDs provide superior light output for excellent readability in sunlight and are extremely reliable. AlInGaP LED technology provides extremely stable light output over long periods of time. Precision Optical Performance lamps utilize the aluminum indium gallium phosphide (AlInGaP) technology.

These LED lamps are tinted, diffused, T-1³/₄ packages incorporating second generation optics producing well defined radiation patterns at specific viewing cone angles.

SunPower Series

HLMP-EL55	HLMP-EL57
HLMP-EH55	HLMP-EH57
HLMP-EG55	HLMP-EG57

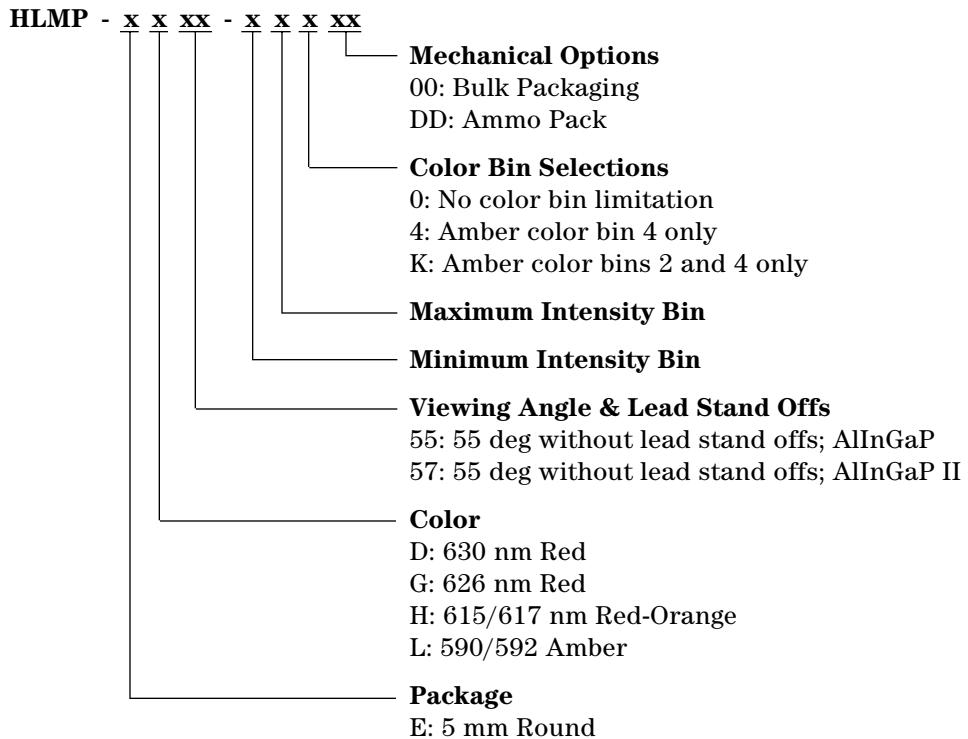


There are two families of amber, red, and red-orange lamps; AlInGaP and the higher performance AlInGaP II.

The high maximum LED junction temperature limit of $+130^\circ\text{C}$ enables high temperature operation in bright sunlight conditions.

These lamps are available in two package options to give the designer flexibility with device mounting.

Part Numbering System



Device Selection Guide (AlInGaP)

Typical Viewing Angle $2\theta_{1/2}$ (Deg.) ^[4]	Color and Dominant Wavelength (nm), Typ. ^[3]	Lamps Without Standoffs on Leads (Outline Drawing A)	Luminous Intensity I_v (mcd) ^[1,2] @20 mA	
			Min.	Max.
55°	Amber 590	HLMP-EL55-GK000	140	400
	Red-Orange 615	HLMP-EH55-GK000	140	400
	Red 626	HLMP-EG55-GK000	140	400

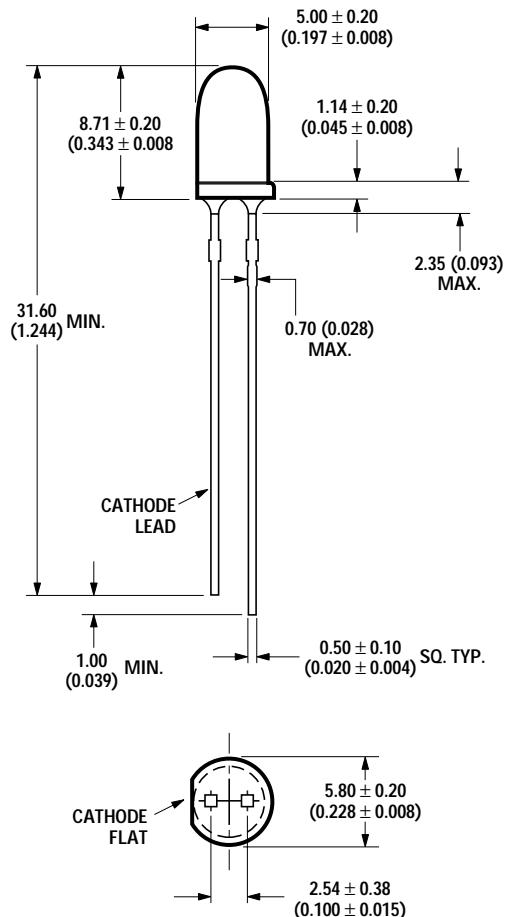
Device Selection Guide (AlInGaP II)

Typical Viewing Angle $2\theta_{1/2}$ (Deg.) ^[4]	Color and Dominant Wavelength (nm), Typ. ^[3]	Lamps Without Standoffs on Leads (Outline Drawing A)	Luminous Intensity I_v (mcd) ^[1,2] @20 mA	
			Min.	Max.
55°	Amber 592	HLMP-EL57-LP000	400	1150
	Red-Orange 617	HLMP-EH57-LP000	400	1150
	Red 630	HLMP-ED57-LP000	400	1150

Notes:

1. The luminous intensity is measured on the mechanical axis of the lamp package.
2. The optical axis is closely aligned with the package mechanical axis.
3. The dominant wavelength, λ_d , is derived from the CIE Chromaticity Diagram and represents the color of the lamp.
4. $\theta_{1/2}$ is the off-axis angle where the luminous intensity is one half the on-axis intensity.

Package Dimensions



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS (INCHES).
2. LEADS ARE MILD STEEL, SOLDER DIPPED.
3. TAPERED SHOWN AT TOP OF LEADS (BOTTOM OF LAMP PACKAGE) INDICATE AN EPOXY MENISCUS THAT MAY EXTEND ABOUT 1 mm (0.040 in.) DOWN THE LEADS.
4. RECOMMENDED PC BOARD HOLE DIAMETERS:
LAMP PACKAGE WITHOUT STAND-OFFS: FLUSH MOUNTING AT BASE OF
LAMP PACKAGE = 1.143/1.067 (0.044/0.042).

Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

DC Forward Current ^[1,2,3]	50 mA
Peak Pulsed Forward Current ^[2,3]	100 mA
Average Forward Current ^[3]	30 mA
Reverse Voltage ($I_R = 100 \mu\text{A}$)	5 V
LED Junction Temperature	130°C
Operating Temperature	-40°C to $+100^\circ\text{C}$
Storage Temperature	-40°C to $+120^\circ\text{C}$
Through-the-Wave Solder Temperature	250°C for 3 seconds [1.59 mm (0.060 in.) below body]

Notes:

1. Derate linearly as shown in Figure 4.
2. For long term performance with minimal light output degradation, drive currents between 10 mA and 30 mA are recommended. For more information on recommended drive conditions, please refer to Application Brief I-024 (5966-3087E).
3. Please contact your Agilent Technologies sales representative about operating currents below 10 mA.

Electrical/Optical Characteristics at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Forward Voltage Amber ($\lambda_d = 590 \text{ nm}$) Amber ($\lambda_d = 592 \text{ nm}$) Red-Orange ($\lambda_d = 615 \text{ nm}$) Red-Orange ($\lambda_d = 617 \text{ nm}$) Red ($\lambda_d = 626 \text{ nm}$) Red ($\lambda_d = 630 \text{ nm}$)	V_F		2.02 2.15 1.94 2.08 1.90 2.00	2.4 2.4 2.4 2.4 2.4 2.4	V	$I_F = 20 \text{ mA}$
Reverse Voltage	V_R	5	20		V	$I_R = 100 \mu\text{A}$
Peak Wavelength Amber ($\lambda_d = 590 \text{ nm}$) Amber ($\lambda_d = 592 \text{ nm}$) Red-Orange ($\lambda_d = 615 \text{ nm}$) Red-Orange ($\lambda_d = 617 \text{ nm}$) Red ($\lambda_d = 626 \text{ nm}$) Red ($\lambda_d = 630 \text{ nm}$)	λ_{PEAK}		592 594 621 623 635 639		nm	Peak of Wavelength of Spectral Distribution at $I_F = 20 \text{ mA}$
Spectral Halfwidth	$\Delta\lambda_{1/2}$		17		nm	Wavelength Width at Spectral Distribution 1/2 Power Point at $I_F = 20 \text{ mA}$
Speed of Response	τ_s		20		ns	Exponential Time Constant, e^{-t/τ_s}
Capacitance	C		40		pF	$V_F = 0, f = 1 \text{ MHz}$
Thermal Resistance	$R\theta_{J-\text{PIN}}$		240		°C/W	LED Junction-to-Cathode Lead
Luminous Efficacy ^[1] Amber ($\lambda_d = 590 \text{ nm}$) Amber ($\lambda_d = 592 \text{ nm}$) Red-Orange ($\lambda_d = 615 \text{ nm}$) Red-Orange ($\lambda_d = 617 \text{ nm}$) Red ($\lambda_d = 626 \text{ nm}$) Red ($\lambda_d = 630 \text{ nm}$)	η_v		480 500 260 235 150 155		lm/W	Emitted Luminous Power/Emitted Radiant Power

Note:

1. The radiant intensity, I_e , in watts per steradian, may be found from the equation $I_e = I_v/\eta_v$, where I_v is the luminous intensity in candelas and η_v is the luminous efficacy in lumens/watt.

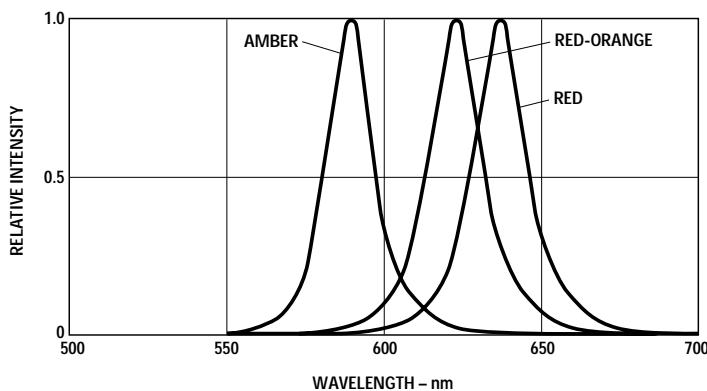


Figure 1. Relative Intensity vs. Peak Wavelength.

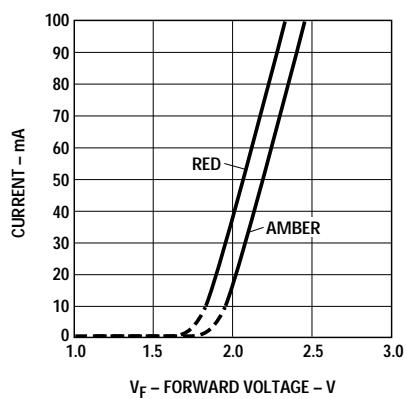


Figure 2. Forward Current vs. Forward Voltage.

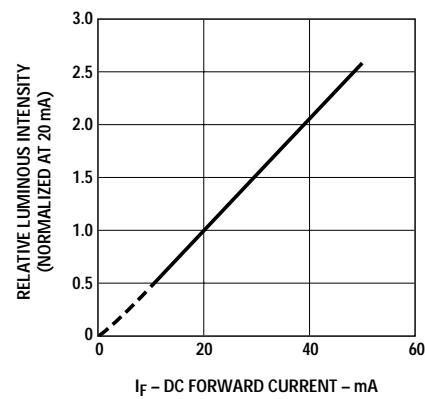


Figure 3. Relative Luminous Intensity vs. Forward Current.

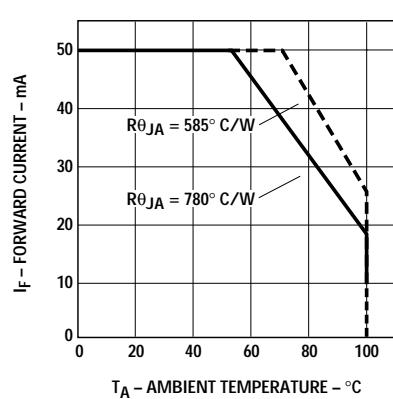


Figure 4. Maximum Forward Current vs. Ambient Temperature. Derating Based on $T_{JMAX} = 130^\circ\text{C}$.

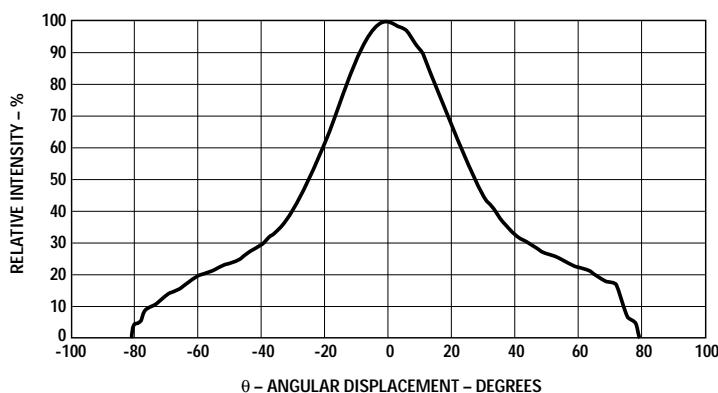


Figure 5. Representative Spatial Radiation Pattern for 55° Viewing Angle Lamps.



**Intensity Bin Limits
(mcd at 20 mA)**

Bin Name	Min.	Max.
G	140	180
H	180	240
J	240	310
K	310	400
L	400	520
M	520	680
N	680	880
P	880	1150

Tolerance for each bin limit is \pm 15%.

**Amber Color Bin Limits
(nm at 20 mA)**

Bin Name	Min.	Max.
1	584.5	587.0
2	587.0	589.5
4	589.5	592.0
6	592.0	594.5

Tolerance for each bin limit is \pm 0.5 nm.

Note:

1. Bin categories are established for classification of products. Products may not be available in all bin categories.

www.agilent.com/semiconductors

For product information and a complete list of distributors, please go to our web site.

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Data subject to change.

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